

## Chapter 2

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**2.3 Conduction in gold** Gold is in the same group as Cu and Ag. Assuming that each Au atom donates one conduction electron, calculate the drift mobility of the electrons in gold at 22° C. What is the mean free path of the conduction electrons if their mean speed is  $1.4 \times 10^6 \text{ m s}^{-1}$ ? (Use  $\rho_0$  and  $\alpha_0$  in Table 2.1.)

Table 2.1 at 0°C (273 K) is  $\rho_0 = 22.8 \text{ n}\Omega \text{ m}$ ,  $\alpha_0 = 1/251 \text{ K}^{-1}$

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### 2.4 Effective number of conduction electrons per atom

- a. Electron drift mobility in tin (Sn) is  $3.9 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ . The room temperature ( $20^\circ \text{C}$ ) resistivity of Sn is about  $110 \text{ n}\Omega \text{ m}$ . Atomic mass  $M_{\text{at}}$  and density of Sn are  $118.69 \text{ g mol}^{-1}$  and  $7.30 \text{ g cm}^{-3}$ , respectively. How many “free” electrons are donated by each Sn atom in the crystal? How does this compare with the position of Sn in Group IVB of the Periodic Table?
- b. Consider the resistivity of few selected metals from Groups I to IV in the Periodic Table in Table 2.7. Calculate the number of conduction electrons contributed per atom and compare this with the location of the element in the Periodic Table. What is your conclusion?

**Table 2.7** Selection of metals from Groups I to IV in the Periodic Table

Metal	Periodic Group	Valency	Density ( $\text{g cm}^{-3}$ )	Resistivity ( $\text{n}\Omega \text{ m}$ )	Mobility ( $\text{cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ )
Na	IA	1	0.97	42.0	53
Mg	IIA	2	1.74	44.5	17
Ag	IB	1	10.5	15.9	56
Zn	IIB	2	7.14	59.2	8
Al	IIIB	3	2.7	26.5	12
Sn	IVB	4	7.30	110	3.9
Pb	IVB	4	11.4	206	2.3

NOTE: Mobility from Hall-effect measurements.

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**2.12 Electrical and thermal conductivity of Ag** The electron drift mobility in silver has been measured to be  $56 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  at  $27^\circ\text{C}$ . The atomic mass and density of Ag are given as  $107.87 \text{ amu}$  or  $\text{g mol}^{-1}$  and  $10.50 \text{ g cm}^{-3}$ , respectively.

- a. Assuming that each Ag atom contributes one conduction electron, calculate the resistivity of Ag at  $27^\circ\text{C}$ . Compare this value with the measured value of  $1.6 \times 10^{-8} \Omega \text{ m}$  at the same temperature and suggest reasons for the difference.
- b. Calculate the thermal conductivity of silver at  $27^\circ\text{C}$  and at  $0^\circ\text{C}$ .

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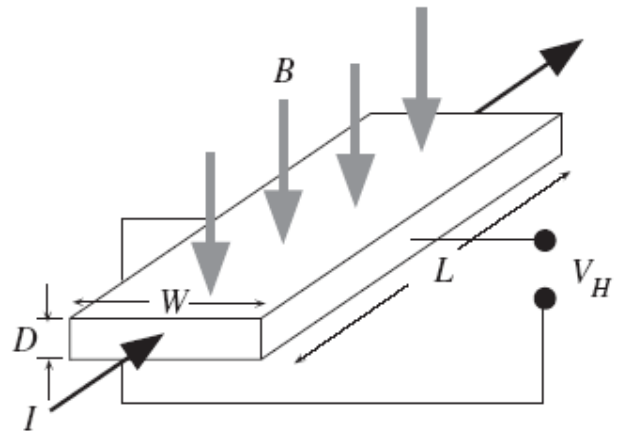
**2.20 The Hall effect** Consider a rectangular sample, a metal or an  $n$ -type semiconductor, with a length  $L$ , width  $W$ , and thickness  $D$ . A current  $I$  is passed along  $L$ , perpendicular to the cross-sectional area  $WD$ . The face  $W \times L$  is exposed to a magnetic field density  $B$ . A voltmeter is connected across the width, as shown in Figure 2.40, to read the Hall voltage  $V_H$ .

- a. Show that the Hall voltage recorded by the voltmeter is

$$V_H = \frac{IB}{Den} \quad \text{Hall voltage}$$

- b. Consider a 1-micron-thick strip of gold layer on an insulating substrate that is a candidate for a Hall probe sensor. If the current through the film is maintained at constant 100 mA, what is the magnetic field that can be recorded per  $\mu\text{V}$  of Hall voltage?

**Figure 2.40** Hall effect in a rectangular material with length  $L$ , width  $W$ , and thickness  $D$ . The voltmeter is across the width  $W$ .



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